XC9120/XC9121/XC9122 Series

Step-Up DC/DC Controller IC, MAXDUTY: 93%

☆Green Operation Compatible

■GENERAL DESCRIPTION

XC9120/XC9121/XC9122 Series are PWM, PWM/PFM auto/external switching controlled step-up DC/DC converter controller ICs. Since maximum duty ratio is as large as 93%, the series is the best for the applications used as high step-up ratios, such as the LCD panels and OLED. In this series, even if it is a high step-up ratio, the output voltage stabilized at high efficiency can be obtained.

With 0.9V (±2.0%) of reference voltage supply internal, and using external resistors, R_{FB1} and R_{FB2}, output voltage can be set up freely within a range of 1.5V to 30V. For a current sense, with the use of RSENSE, ceramic capacitors can be used as load capacitors and allows for lower output ripple and reduced PCB area requirements.

Control automatically switches from PWM to PFM during light loads with the XC9121 series and the XC9122 series can switch the control from PWM to PFM using external signals depending on the circuit conditions.

During stand-by (when the CE pin is low), all circuits are shutdown to reduce current consumption to as low as 1.0μA or less.

■APPLICATIONS

●Power Supply for the LCDs.

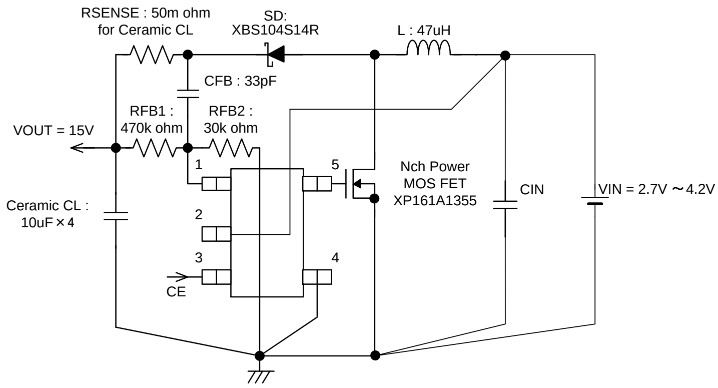
●Organic electroluminescence display (OELD)

■FEATURES

Input Voltage Range	: 0.9V~6.0V
Operating Voltage Range	: 1.8V~6.0V
Output Voltage Range	: 1.5V~30V (externally set)
	Reference voltage 0.9V (±2.0%)
Oscillation Frequency	: 100kHz (±15%)
Output Current	: ≥80mA (V_{IN}=3.6V, V_{OUT}=15V)*
Control	: XC9120 (PWM)
	: XC9121 (PWM/PFM Automatic)
	: XC9122 (PWM/PFM Externally)
High Efficiency	: 85% (TYP.)
	: (V_{IN}=3.6V, V_{OUT}=15V, I_{OUT}=10mA)*
Stand-by Function	: I_{STB}=1.0μA (MAX.)
Load Capacitors	: Low ESR capacitor compatible
Maximum Duty Cycle	: 93% (TYP.) for High Step-up Ratio
Packages	: SOT-25, USP-6C

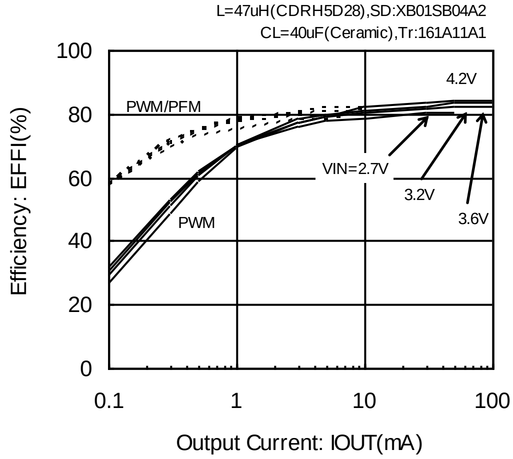
*** When using external components showing in the circuit below.**

■TYPICAL APPLICATION CIRCUIT

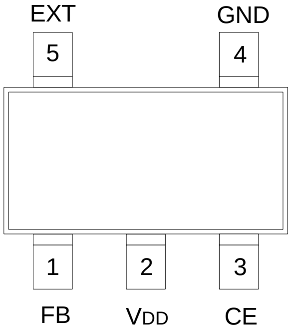


■TYPICAL PERFORMANCE CHARACTERISTICS

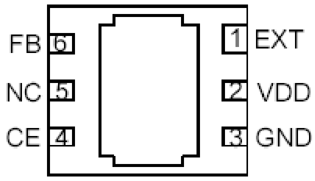
XC9122D091 (100kHz, 15.0V)



■PIN CONFIGURATION



SOT-25 (TOP VIEW)



USP-6C (BOTTOM VIEW)

* The dissipation pad for the USP-6C package should be solder-plated in recommended mount pattern and metal masking so as to enhance mounting strength and heat release.
If the pad needs to be connected to other pins, it should be connected to the V_{DD} pin (Pin #2).

■PIN ASSIGNMENT

PIN NUMBER		PIN NAME	FUNCTION
SOT-25	USP-6C		
1	6	FB	Output Voltage Setting Resistor Connection
2	2	V_{DD}	Supply Voltage
3	4	CE	Chip Enable (Operates when "H" Level)
		CE (/PWM)	PWM/PFM Switch*
4	3	GND	Ground
5	1	EXT	External Transistor Drive Connection
-	5	NC	No Connection

* The XC9122 series combines the CE pin and PWM/PFM switch pin.

■FUNCTION

XC9120/9121 Series

CE PIN	IC OPERATIONAL STATE
H	Operation
L	Shut-Down

XC9122 Series

CE/PWM PIN		IC OPERATIONAL STATE
H	More than V_{DD} - 0.2V	Operation (PWM control)
M	0.65 ~ V_{DD} - 1.0V	Operation (PWM/PFM automatic switching control
L	0 ~ 0.2V	Shut-Down

■ PRODUCT CLASSIFICATION

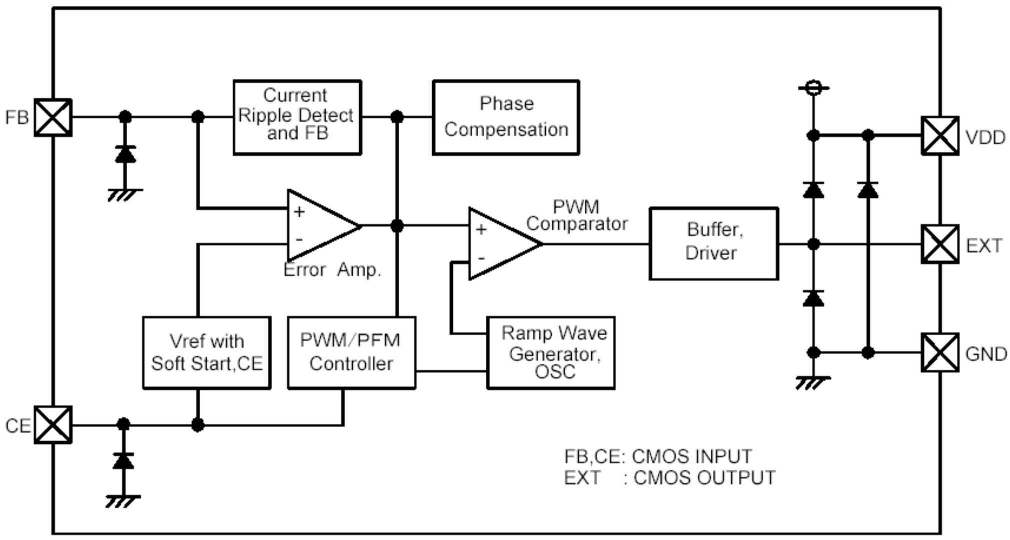
●Ordering Information

XC9120①②③④⑤⑥-⑦[*1]: PWM Control
XC9121①②③④⑤⑥-⑦[*1]: PWM/PFM Automatic Switching Control
XC9122①②③④⑤⑥-⑦[*1]: PWM/PFM Externally Switching Control

DESIGNATOR	DESCRIPTION	SYMBOL	DESCRIPTION
①	Type of DC/DC Controller	D	No current limiter
② ③	Output Voltage	09	FB Voltage (ex. FB Voltage=0.9V→②=0, ③=9)
④	Oscillation Frequency	1	100kHz
⑤⑥-⑦	Packages (Oder Unit)	MR-G	SOT-25 (3,000/Reel)
		ER-G	USP-6C (3,000/Reel)

(*1) The “-G” suffix indicates that the products are Halogen and Antimony free as well as being fully EU RoHS compliant.

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

Ta=25℃

PARAMETER		SYMBOL	RATINGS	UNIT
V_{DD} Pin Voltage		V_{DD}	-0.3 ~ 12.0	V
FB Pin Voltage		V_{FB}	-0.3 ~ 12.0	V
CE Pin Voltage		V_{CE}	-0.3 ~ 12.0	V
EXT Pin Voltage		V_{EXT}	-0.3 ~ V_{DD} + 0.3	V
EXT Pin Current		I_{EXT}	±100	mA
Power Dissipation	SOT-25	Pd	250	mW
			760 (JESD51-7 board)(*1)	
	USP-6C		120	
			1250 (JESD51-7 board)(*1)	
Operating Temperature Range		Topr	-40 ~ 85	℃
Storage Temperature Range		Tstg	-55 ~ 125	℃

■ELECTRICAL CHARACTERISTICS

(f_{OSC}=100kHz) Ta=25℃

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	CIRCUIT
FB Voltage	V_{FB}		0.882	0.900	0.918	V	④
Supply Voltage Range (*1)	V_{DD}		1.8	-	6.0	V	①
Output Voltage Setting Range	V_{OUTSET}	Recommended circuit using 2SD1628, V_{IN}=V_{OUTSET} × 0.6, V_{DD}=3.0V, I_{OUT}=1.0mA	1.5	-	30.0	V	②
Operation Start Voltage	V_{ST1}	Recommended circuit using 2SD1628 V_{OUT}=3.3V, I_{OUT}=1.0mA	-	-	0.9	V	③
Oscillation Start Voltage (*1)	V_{ST2}	No external components, CE connected to V_{DD}, Voltage applied, FB=0V	-	-	0.8	V	④
Operation Hold Voltage	V_{HLD}	Recommended circuit using 2SD1628 V_{OUT}=3.3V, I_{OUT}=1.0mA	-	-	0.7	V	③
Supply Voltage 1	I_{DD1}	Same as V_{ST2}, V_{DD}=3.0V	-	25	50	μA	④
Supply Voltage 2	I_{DD2}	Same as I_{DD1}, FB=1.2V	-	13	30	μA	④
Stand-by Current	I_{STB}	Same as I_{DD1}, CE=0V	-	-	1.0	μA	⑤
Oscillation Frequency	f_{OSC}	Same as I_{DD1}	85	100	115	kHz	④
Maximum Duty Ratio	MAXDTY	Same as I_{DD1}	89	93	96	%	④
PFM Duty Ratio	PFMDTY	No Load (XC9121D, XC9122D types)	24	32	40	%	⑥
Efficiency (*2)	EFFI	I_{OUT}=10mA	-	85	-	%	①
Soft-Start Time	t_{SS}		5.0	10.0	20.0	ms	①
CE "H" Voltage	V_{CEH}	Same as I_{DD1}	0.65	-	-	V	⑤
CE "L" Voltage	V_{CEL}	Same as I_{DD1}	-	-	0.20	V	⑤
EXT "H" ON Resistance	R_{EXTH}	Same as I_{DD1}, V_{EXT}=V_{OUT}-0.4V	-	24	36	Ω	④
EXT "L" ON Resistance	R_{EXTL}	Same as I_{DD1}, V_{EXT}=0.4V	-	16	24	Ω	④
PWM 'H' Voltage (*3)	V_{PWMH}	I_{OUT}=1mA (XC9122D type)	V_{DD}-0.2	-	-	V	①
PWM 'L' Voltage (*3)	V_{PWML}	I_{OUT}=1mA (XC9122D type)	-	-	V_{DD}-1.0	V	①
CE "H" Current	I_{CEH}	Same as I_{DD2}, CE=V_{DD}	-	-	0.1	μA	⑤
CE "L" Current	I_{CEL}	Same as I_{DD2}, CE=0V	-	-	-0.1	μA	⑤
FB "H" Current	I_{FBH}	Same as I_{DD2}, FB=V_{DD}	-	-	0.1	μA	⑤
FB "L" Current	I_{FBL}	Same as I_{DD2}, FB=0V	-	-	-0.1	μA	⑤

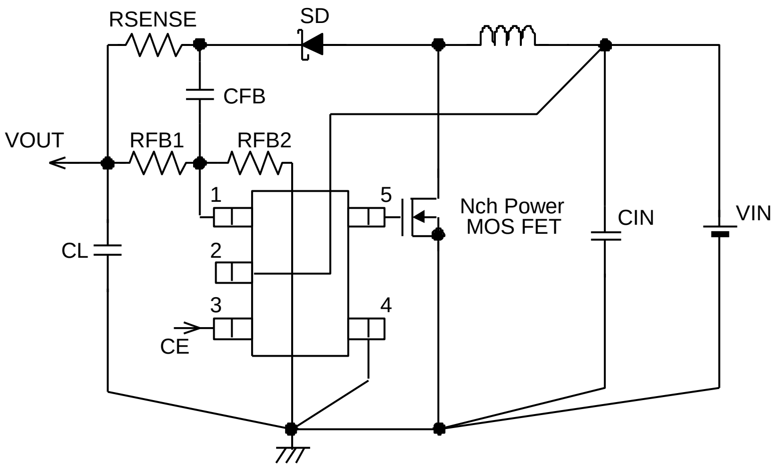
Test Conditions: Unless otherwise stated, CL: ceramic, recommended MOSFET should be connected.
When V_{OUT} is set at 15V, V_{IN}=V_{DD}=3.6V.

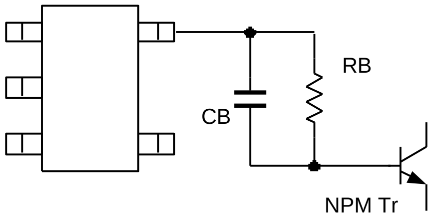
NOTE:
*1: Although the IC starts step-up operations from a V_{DD}=0.8V, the output voltage and oscillation frequency are stabilized at $V_{DD}\geq$1.8V. Therefore, a V_{DD} of more than 1.8V is recommended when V_{DD} is supplied from V_{IN} or other power sources.

*2: EFFI: *{(output voltage) x (output current)} / {(input voltage) x (input current)} x 100*

*3: The XC9122 series' CE pin combines PWM/PFM external switch pin. In the operation state, PWM control becomes effective when the CE pin is more than V_{DD}-0.2V. When the CE pin is less than V_{DD}-1.0V and more than VCEH, PWM/PFM automatic switching control becomes effective with 32% duty.

■ TYPICAL APPLICATION CIRCUIT





When obtaining V_{DD} from a source other than V_{IN} (V_{OUT}), please insert a by-pass capacitor C_{DD} between the V_{DD} pin and the GND pin in order to provide stable operations.

Please place C_L and C_{IN} as close as to the V_{OUT} and V_{DD} pins respectively and also close to the GND pin. Strengthen the wiring sufficiently.

R_{SENSE} should be removed and shorted when the C_L capacitor except for ceramic or low ESR capacitor is used.

Insert R_B and C_B when using a bipolar NPN transistor.

■ OPERATIONAL EXPLANATION

The XC9120/XC9121/XC9122 series consists of a reference voltage source, ramp wave circuit, error amplifier, PWM comparator, phase compensation circuit, and current limiter circuit.
The series ICs compare, using the error amplifier, the voltage of the internal voltage reference source with the feedback voltage from the FB pin. Phase compensation is performed on the resulting error amplifier output, to input a signal to the PWM comparator to determine the turn-on time during PWM operation.
The PWM comparator compares, in terms of voltage level, the signal from the error amplifier with the ramp wave from the ramp wave circuit and delivers the resulting output to the buffer driver circuit to cause the EXT pin to output a switching duty cycle. This process is continuously performed to ensure stable output voltage.

<Error Amp.>
Error amplifier is designed to monitor the output voltage, comparing the feedback voltage (FB) with the reference voltage Vref. In response to feedback of a voltage lower than the reference voltage Vref, the output voltage of the error amp. decreases.

<OSC Generator>
The circuit generates the internal reference clock. The frequency is set to 100kHz (TYP.).

<Ramp Wave Generator>
The ramp wave generator generates a saw-tooth waveform based on outputs from the OSC Generator.

<PWM Comparator>
The PWM comparator compares outputs from the error amp. and saw-tooth waveform. When the voltage from the error amp's output is low, the external switch will be set to ON.

<PWM/PFM Comparator>
The circuit generates PFM pulses.
The XC9122 series can switch PWM control and PWM/PFM switching control by external signal. The PWM/PFM automatic switching control becomes effective when the voltage of the CE pin is less than V_{DD}-1.0V, and the control switches between PWM and PFM automatically depending on the load. The PWM/PFM control turns into the PFM control when threshold voltage becomes lower than voltage of error amps. The PWM control becomes effective when the CE pin voltage is more than V_{DD}-0.2V. Noise is easily reduced with the PWM control since the switching frequency is fixed. Because of this, the series gives the best control suitable for your application.

<Vref with Soft Start>
The reference voltage, Vref (FB pin voltage) =0.9V, is adjusted and fixed by laser trimming (for output voltage settings, please refer to the output voltage setting.). Soft-start circuit protects against inrush current, when the power is switched on, and also protects against voltage overshoot. It should be noted, however, that this circuit does not protect the load capacitor (C_L) form inrush current. With the Vref voltage limited and depending on the input to the error amps, the operation maintains a balance between the two inputs of the error amps and controls the EXT pin's ON time so that it does not increase more than is necessary.

<Enable Function>
The function controls the operation and shutdown of the IC. When the voltage of the CE pin is 0.2V or less, the mode will be disable, the channel's operations will stop and the EXT pin will be kept at a low level (the external N-ch MOSFET will be OFF). When the IC is in a state of disable, current consumption will be no more than 1.0 μA. When the CE pin's voltage is 0.65V or more, the mode will be enabled and operations will recommence.

■ OPERATIONAL EXPLANATION (Continued)

<Output Voltage Setting>

Output voltage can be set by adding external split resistors. Output voltage is determined by the following equation, based on the values of R_{FB1} and R_{FB2}. The sum of R_{FB1} and R_{FB2} should normally be 2MΩ.

$$V_{OUT} = 0.9 \times (R_{FB1} + R_{FB2}) / R_{FB2}$$

The value of CFB1, speed-up capacitor for phase compensation, should result in fzfb = $1/(2\times\pi\times C_{FB}\times R_{FB1})$ equal to 15kHz. Adjustments are required between 5kHz to 30kHz depending on the application, value of inductance (L), and value of load capacitance (C_L).

ex.) Output Voltage Setting

V_{OUT} (V)	R_{FB1} (kΩ)	R_{FB2} (kΩ)	C_{FB} (pF)	V_{OUT} (V)	R_{FB1} (kΩ)	R_{FB2} (kΩ)	C_{FB} (pF)
30.0	390	12	27	15.0	470	30	22
25.0	270	10	39	10.0	150	15	68
20.0	470	22	22	7.0	150	22	68
18.0	510	27	18	3.3	150	56	68

<The Use of Ceramic Capacitor CL>

The circuit of the XC9120 series is organized by a specialized circuit, which reenacts negative feedback of both voltage and current. Also by insertion of approximately 50mΩ of a low and inexpensive sense resistor as current sense, a high degree of stability is possible even using a ceramic capacitor, a condition which used to be difficult to achieve. Compared to a tantalum condenser, because the series can be operated in a very small capacity, it is suited to use of the ceramic capacitor, which is cheap and small.

<External Components>

Tr :*When a MOSFET is used
XP161A1355PR (N-Channel Power MOSFET, TOREX)
Note: As the breakdown voltage of XP161A1355PR is 20V, take care with the output voltage. With output voltages over 17V, use the XP161A11A1PR with a breakdown voltage of 30V.
VST1: XP161A1355PR=1.2V (MAX.)
XP161A11A1PR=2.5V (MAX.)

SD :XBS104S14R-G (Schottky Barrier Diode, TOREX)

L, C_L :Please set up as follows according to an operating condition or external components.

L :47μH (CDRH5D28, SUMIDA)
:22μH (CDRH5D28, SUMIDA)

C_L :25V, 10μF (Ceramic type, TMK316BJ106KL, TAIYO YUDEN)
:10V, 10μF (Ceramic type, LMK325BJ106ML, TAIYO YUDEN)
Use the formula below when step-up ratio and output current is large.
$C_L = (C_L \text{ standard value}) \times (I_{OUT}(mA) / 100mA \times V_{OUT} / V_{IN})$

R_{SENSE} :50mΩ (f_{OSC} = 100kHz)

C_L :Tantalum Type

L :47μH (CDRH5D28, SUMIDA)
:22μH (CDRH5D28, SUMIDA)

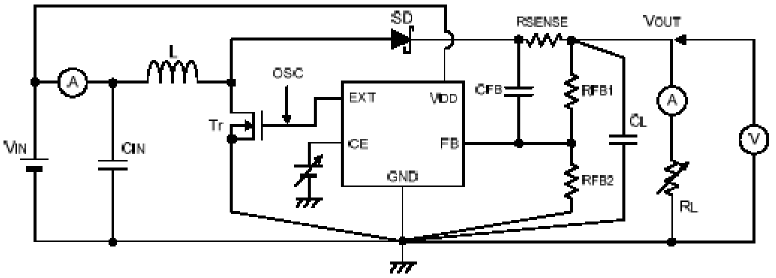
C_L :25V, 47μF (Tantalum type, TAJ series, KYOCERA)
:16V, 47μF (Tantalum type, TAJ series, KYOCERA)
Strengthen appropriately when step-up ratio and output current is large.
$C_L = (C_L \text{ standard value}) \times (I_{OUT}(mA) / 100mA \times V_{OUT} / V_{IN})$

R_{SENSE} :Not required, but short out the wire.

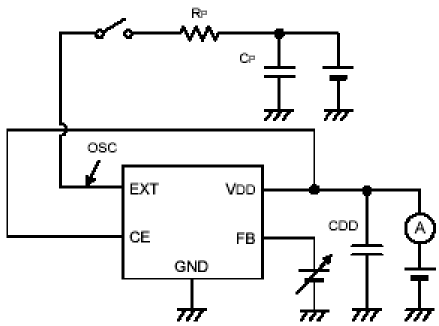
*When a NPN Transistor is used:
2SD1628 (SANYO)
R_B : 500Ω(Adjust with Tr's HSE or load)
C_B : 2200pF (Ceramic type)
$C_B \leqq 1 / (2\pi \times R_B \times f_{OSC} \times 0.7)$

■ TEST CIRCUITS

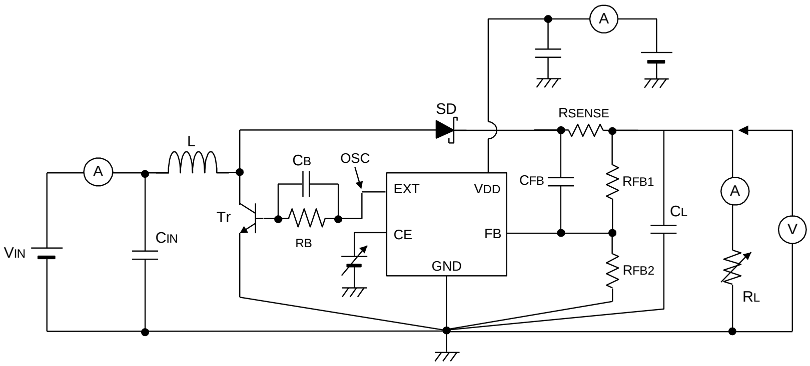
Circuit ①



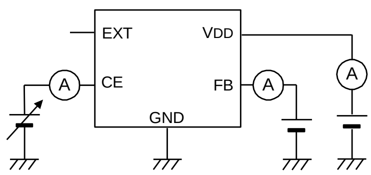
Circuit ④



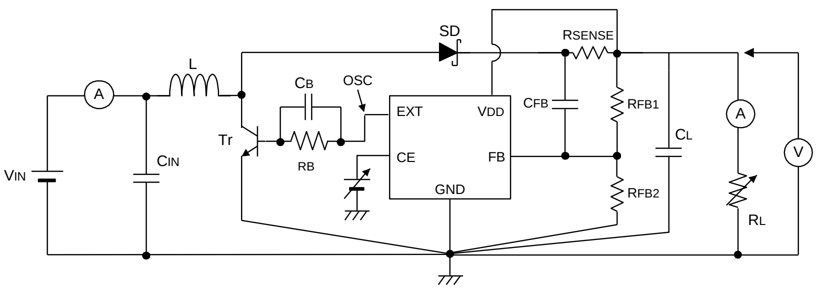
Circuit ②



Circuit ⑤



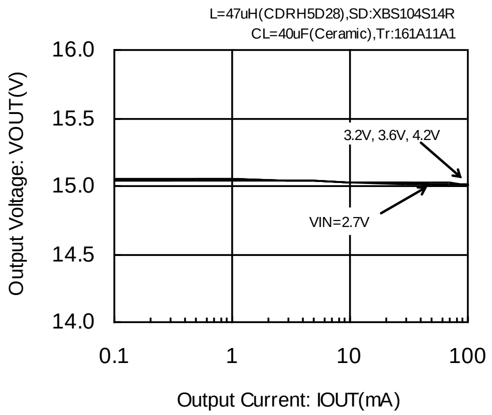
Circuit ③



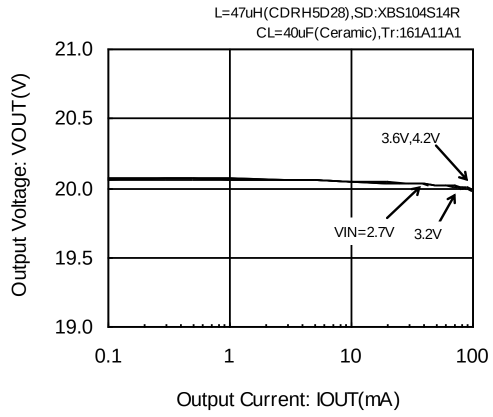
■TYPICAL PERFORMANCE CHARACTERISTICS

(1) Output Voltage vs. Output Current

XC9122D091 (100kHz, 15.0V)

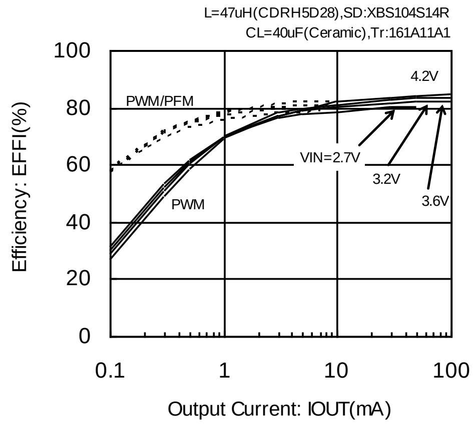


XC9122D091 (100kHz, 20.0V)

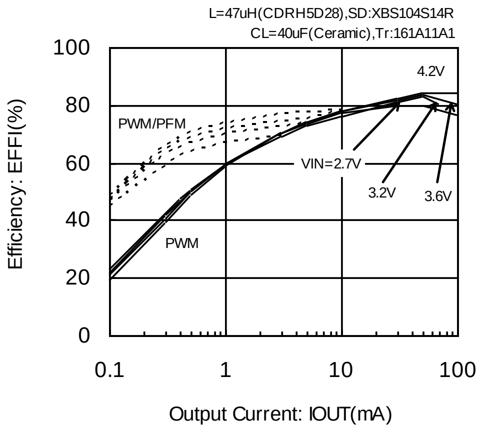


(2) Efficiency vs. Output Current

XC9122D091 (100kHz, 15.0V)

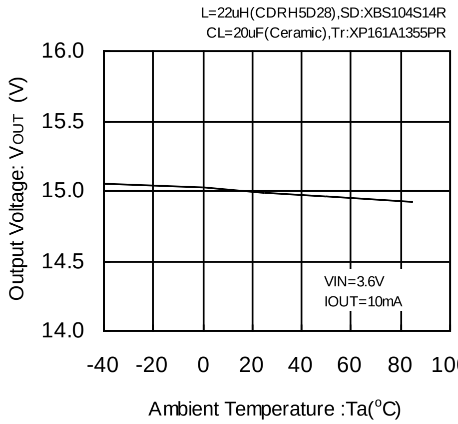


XC9122D091 (100kHz, 20.0V)



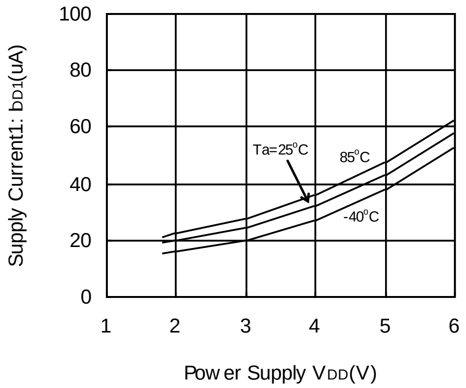
(3) Output Voltage vs. Ambient Temperature

XC9122D091 (100kHz)



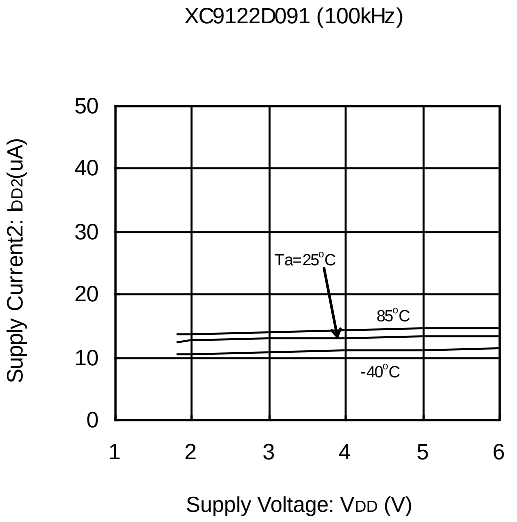
(4) Supply Current 1 vs. Supply Voltage

XC9122D091 (100kHz)

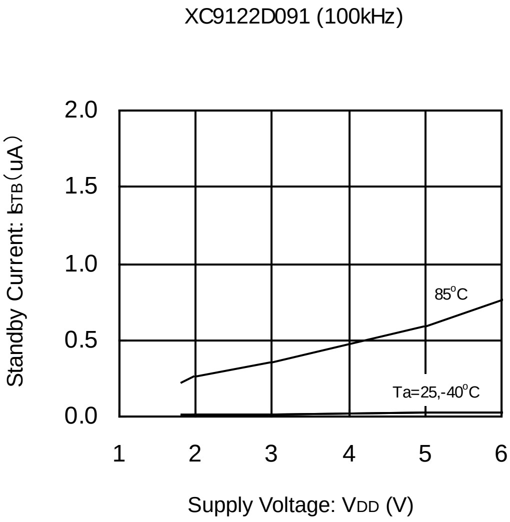


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

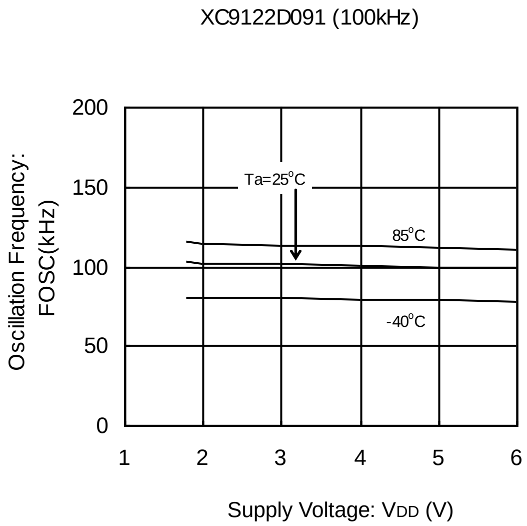
(5) Supply Current 2 vs. Supply Voltage



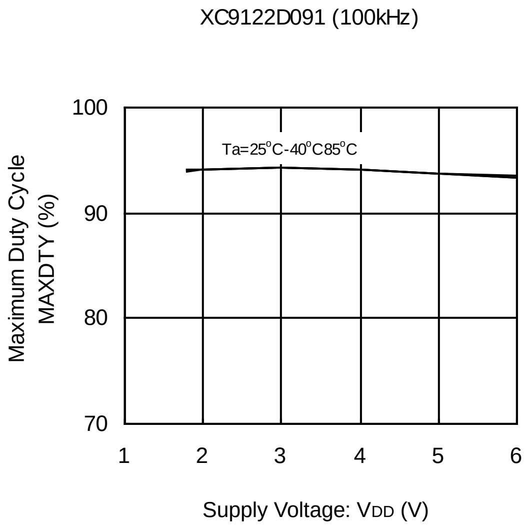
(6) Stand-by Current vs. Supply Voltage



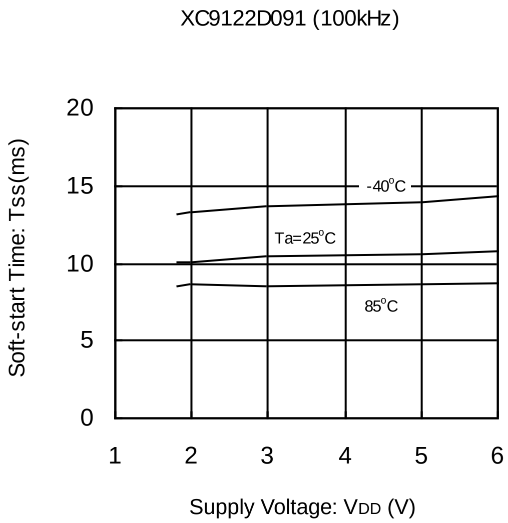
(7) Oscillation Frequency vs. Supply Voltage



(8) Maximum Duty Ratio vs. Supply Voltage



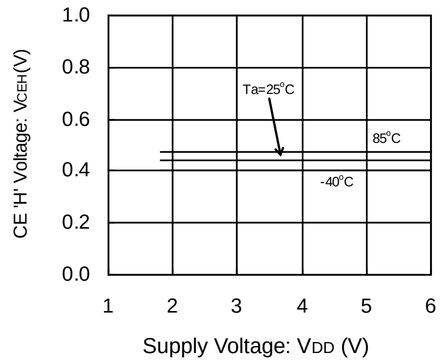
(9) Soft-Start Time vs. Supply Voltage



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

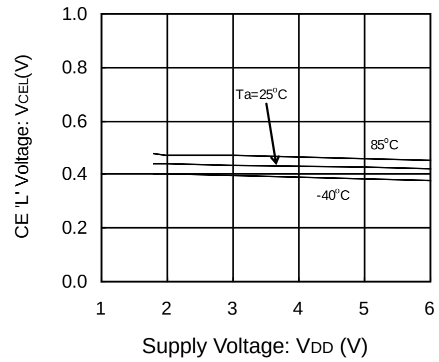
(10) CE "H" Voltage vs. Supply Voltage

XC9122D091 (100kHz)



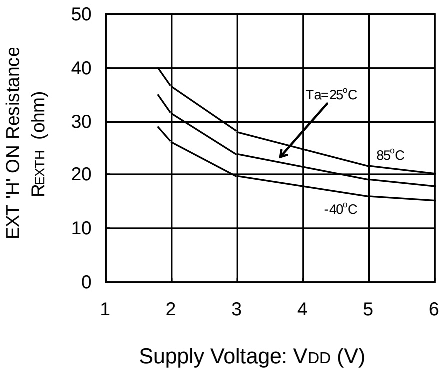
(11) CE "L" Voltage vs. Supply Voltage

XC9122D091 (100kHz)



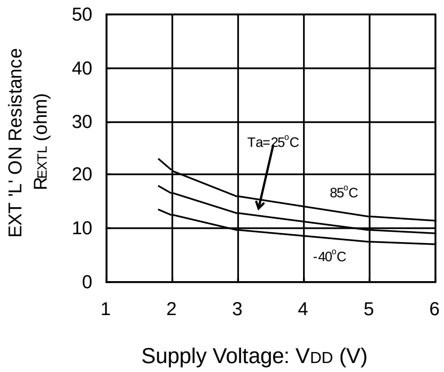
(12) EXT H ON Resistance vs. Supply Voltage

XC9122D091 (100kHz)



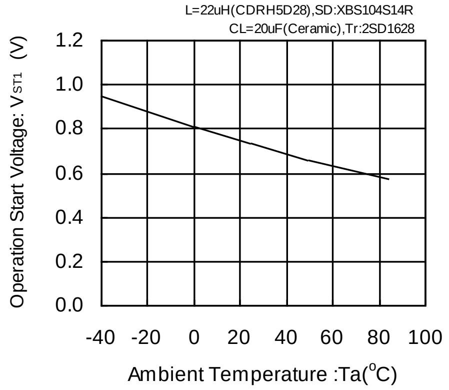
(13) EXT L ON Resistance vs. Supply Voltage

XC9122D091 (100kHz)



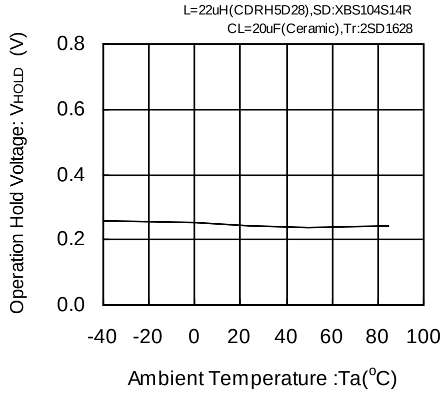
(14) Operation Start Voltage vs. Ambient Temperature

XC9122D091 (100kHz)



(15) Operation Hold Voltage vs. Ambient Temperature

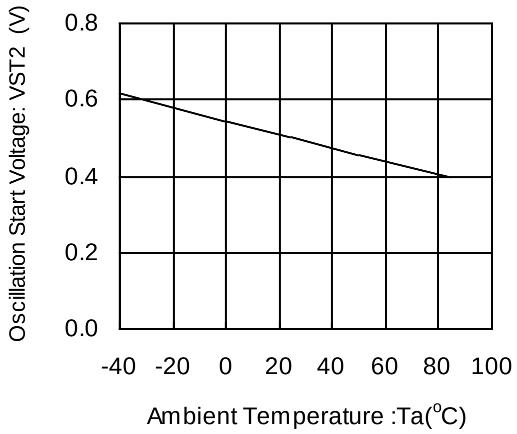
XC9122D091 (100kHz)



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

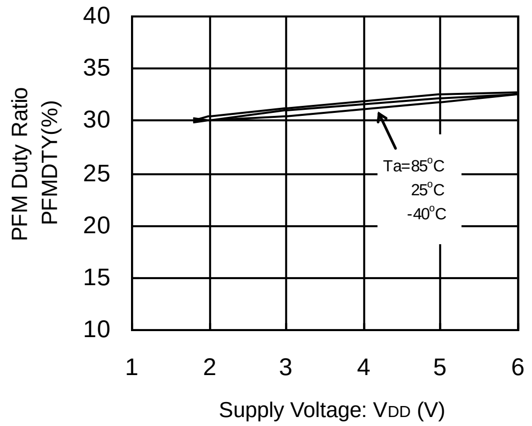
(16) Oscillation Start Voltage vs. Ambient Temperature

XC9122D091 (100kHz)



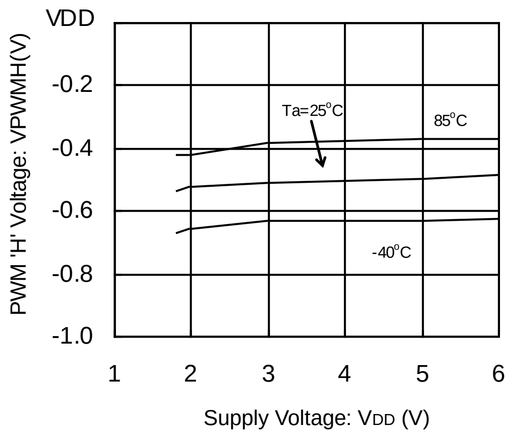
(17) PFM Duty Ratio vs. Supply Voltage

XC9122D091 (100kHz)



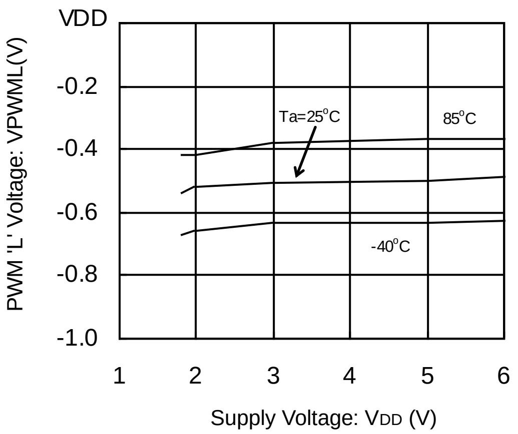
(18) PWM 'H' Voltage vs. Supply Voltage

XC9122D091 (100kHz)



(19) PWM 'L' Voltage vs. Supply Voltage

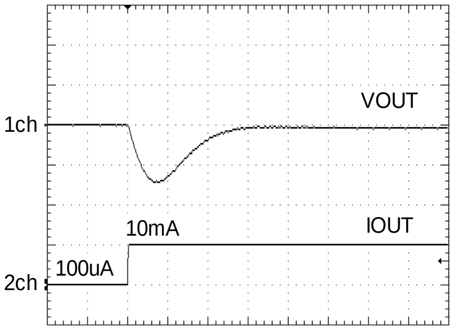
XC9122D091 (100kHz)



■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

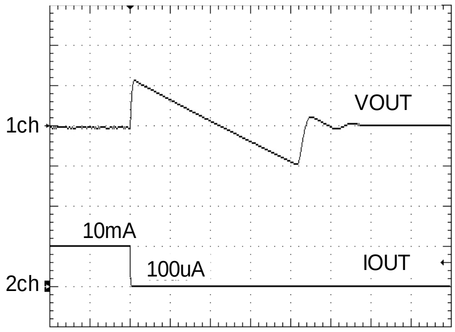
(20) Load Transient Response

VOUT=15V,
VIN=3.6V, IOUT=100uA→10mA



400usec/div.
1ch: VOUT, 100mV/div.
2ch: IOUT, 10mA/div.

VOUT=15V,
VIN=3.6V, IOUT=10mA→100uA



4.0msec/div.
1ch: VOUT, 100mV/div.
2ch: IOUT, 10mA/div.

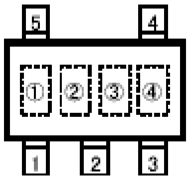
■PACKAGING INFORMATION

For the latest package information go to, www.torexsemi.com/technical-support/packages

PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS
SOT-25	SOT-25 PKG	SOT-25 Power Dissipation
USP-6C	USP-6C PKG	USP-6C Power Dissipation

■ MARKING RULE

●SOT-25



SOT-25
(TOP VIEW)

①Represents product series

MARK	PRODUCT SERIES
M	XC9120x091Mx
N	XC9121x091Mx
P	XC9122x091Mx

②Represents current limit function

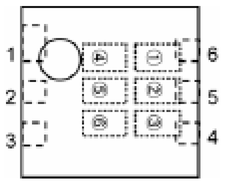
MARK	FUNCTION	PRODUCT SERIES
D	Without Current Limit	XC9120/9121/9122D091Mx

③Represents oscillation frequency

MARK	OSCILLATION FREQUENCY	PRODUCT SERIES
1	100kHz	XC9120/9121/9122x091Mx

④Represents production lot number
0 to 9, A to Z, and inverted 0 to 9, A to Z repeated.
(G, I, J, O, Q, W excepted.)

●USP-6C



USP-6C (TOP VIEW)

①Represents product series

MARK	PRODUCT SERIES
E	XC9120x091Ex
F	XC9121x091Ex
H	XC9122x091Ex

②Represents current limit function

MARK	FUNCTION	PRODUCT SERIES
D	Without current limit	XC9120/9121/9122D091Ex

③④Represents FB voltage

MARK		FB VOLTAGE	PRODUCT SERIES
③	④		
0	9	09	XC9120/9121/9122x091Ex

⑤Represents Oscillation Frequency

MARK	OSCILLATION FREQUENCY	PRODUCT SERIES
1	100kHz	XC9120/9121/9122x091Ex

⑥Represents production lot number
0 to 9, A to Z repeated. (G, I, J, O, Q, W excepted.)
* No inversion is used.

1. The product and product specifications contained herein are subject to change without notice to improve performance characteristics. Consult us, or our representatives before use, to confirm that the information in this datasheet is up to date.

2. The information in this datasheet is intended to illustrate the operation and characteristics of our products. We neither make warranties or representations with respect to the accuracy or completeness of the information contained in this datasheet nor grant any license to any intellectual property rights of ours or any third party concerning with the information in this datasheet.

3. Applicable export control laws and regulations should be complied and the procedures required by such laws and regulations should also be followed, when the product or any information contained in this datasheet is exported.

4. The product is neither intended nor warranted for use in equipment of systems which require extremely high levels of quality and/or reliability and/or a malfunction or failure which may cause loss of human life, bodily injury, serious property damage including but not limited to devices or equipment used in 1) nuclear facilities, 2) aerospace industry, 3) medical facilities, 4) automobile industry and other transportation industry and 5) safety devices and safety equipment to control combustions and explosions. Do not use the product for the above use unless agreed by us in writing in advance.

5. Although we make continuous efforts to improve the quality and reliability of our products; nevertheless Semiconductors are likely to fail with a certain probability. So in order to prevent personal injury and/or property damage resulting from such failure, customers are required to incorporate adequate safety measures in their designs, such as system fail safes, redundancy and fire prevention features.

6. Our products are not designed to be Radiation-resistant.

7. Please use the product listed in this datasheet within the specified ranges.

8. We assume no responsibility for damage or loss due to abnormal use.

9.

TOREX SEMICONDUCTOR LTD.